STRATEGIES ON STORAGE

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 Presenter: Piotr Wysocki, Software Architect, NVM Solutions Group, Intel Corporation
 April 2019

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PERFORMANCE RESULTS ARE BASED ON TESTING AS OF SPECIFIED DATES AND MAY NOT REFLECT ALL PUBLICLY AVAILABLE SECURITY UPDATES. SEE CONFIGURATION DISCLOSURE FOR DETAILS. NO PRODUCT CAN BE ABSOLUTELY SECURE

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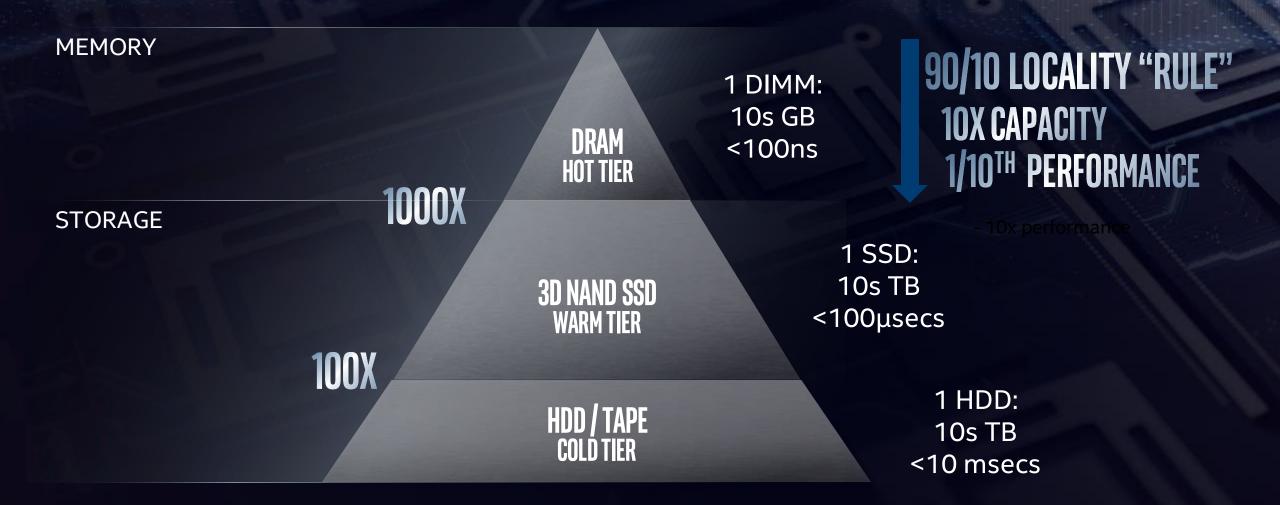
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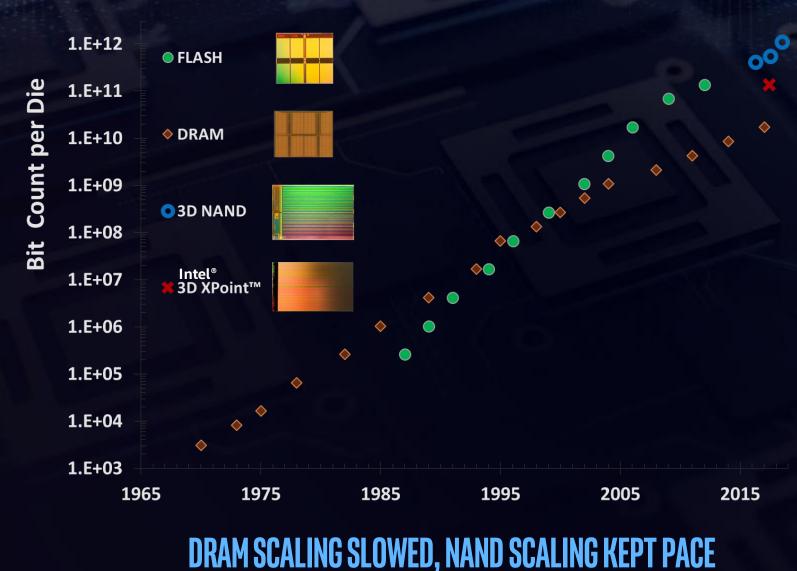
" Ideally one would desire an indefinitely large memory capacity such that any particular ... word would be immediately available. ... It does not seem possible physically to achieve such a capacity. We are therefore forced to recognize the possibility of constructing a hierarchy of memories, each of which has greater capacity than the preceding but which is less quickly accessible."

Preliminary Discussion of the Logical Design of an Electronic Computing Instrument *Arthur Burks, Herman Goldstine and John von Neumann, 1946*

MEMORY AND STORAGE HIERARCHY

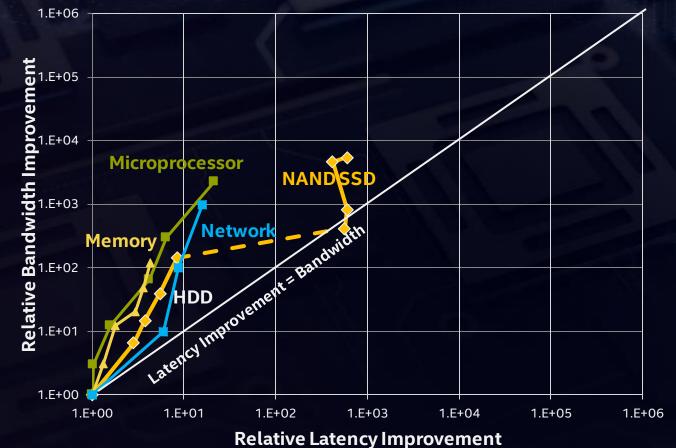


CAPACITY : TECHNOLOGY SCALING



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PERFORMANCE: TECHNOLOGY SCALING

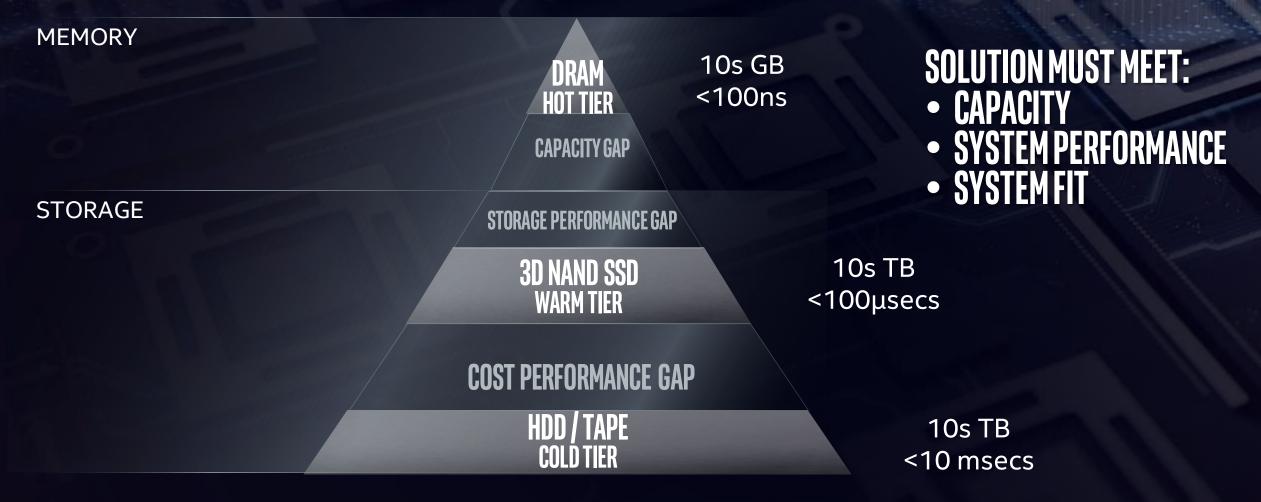


Source: "Latency lags Bandwidth" – David Patterson Comms. of the ACM, Oct 2004 Vol 47, No 10

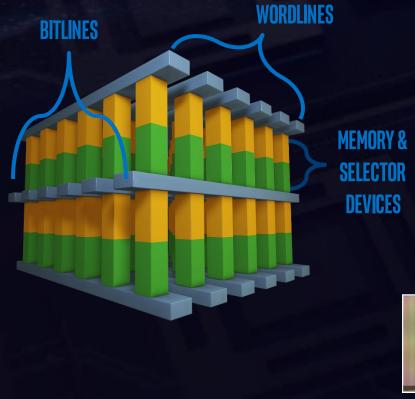
NAND SSD data points added by Intel Based on product brief specifications for Intel NAND SSDs available at <u>www.intel.com</u>

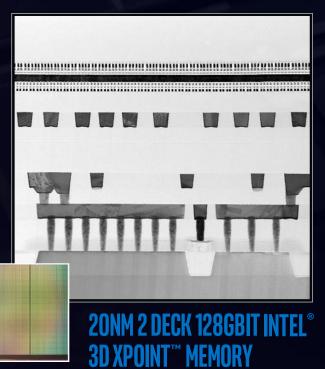
CONCLUSIONS: EVOLUTIONARY IMPROVEMENTS DELIVER IMPROVED BANDWIDTH ONLY NEW TECHNOLOGIES CAN DELIVER IMPROVED LATENCY

MEMORY AND STORAGE HIERARCHY GAPS



A CONVERGENT MEMORY

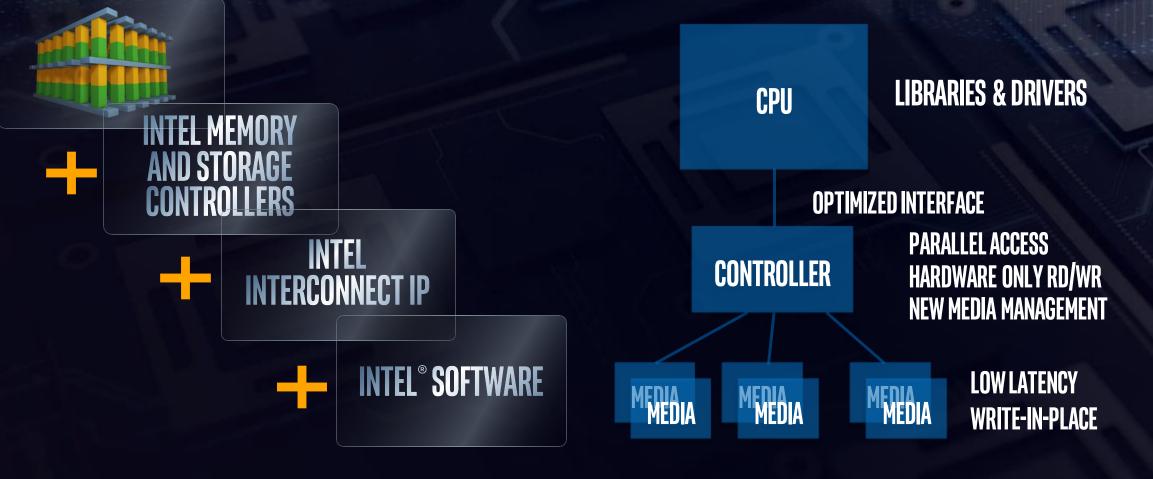




Desirable Attributes: Non-volatile, Low Cost, High Performance

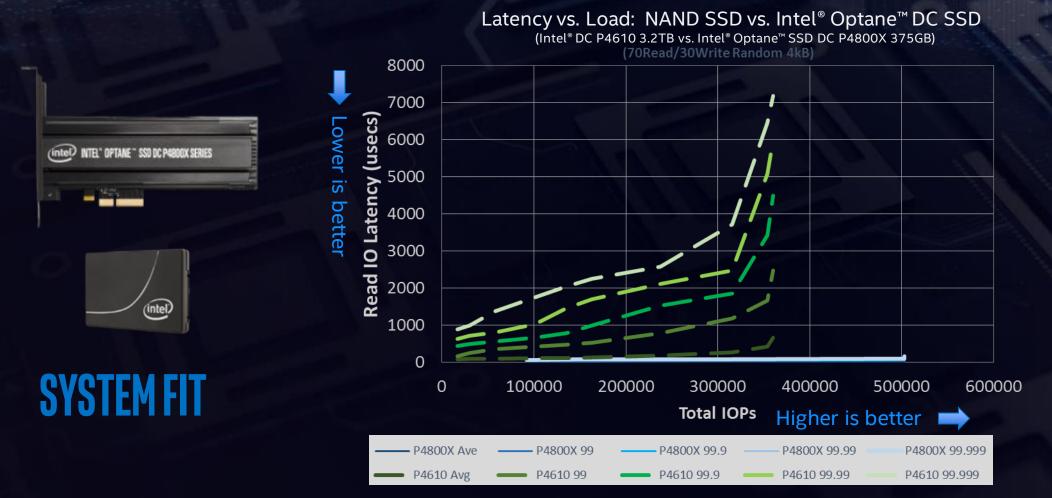
- Memory in atomistic state, not electrostatic
 > Non-Volatile and Scalable
- Simple scalable structure + 3D technology
 → Large Memory Capacity
- Fast switching materials + local low resistance metal interconnect
 Immediately Available
- Individual Cell Access
 → Word Access

INTEL® OPTANETM TECHNOLOGY: BUILDING BLOCKS



PLATFORM LEVEL INNOVATION ENABLES SYSTEM FIT

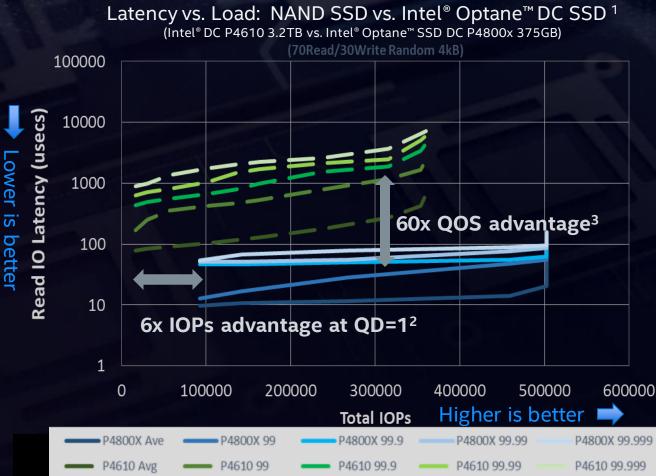
INTEL[®] OPTANE[™] SSD



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Source - Intel-tested: Measured using FIO 3.1. Common Configuration - Intel 2U Server System, OS CentOS 7.5, kernel 4.17.6-1.el7.x86_64, CPU 2 x Intel* Xeon* 6154 Gold @ 3.0GHz (18 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P4800X 10 cores), RAM 256GB DDR4 @ 2666MHz. Configuration - Intel* Optane^{**} SSD DC P4800X 375GB and *Intel* SSD DC P48

SYSTEM LEVEL PERFORMANCE



1 Software and workloads used in performance tests may have been optimized for performance only on Intel microprocessors. Performance tests, souch as SYSmark and MobileMark, are measured using specific computer systems, components, software, operations and functions. Any charge to any of those factors may cause the results to vary. You should consult ofher information and performance tests to assist you in fully evaluating your contemplated purchases, including the performance of that product when combined with other products. For more complete information visit www.intel.com/benchmarks.

Source - Intel+tested: Measured using FIO 3.1. Common Configuration - Intel 2U Server System BIOS: 00.01.0013; ME Firmware: 04.00.04294; BMC Firmware: 1.43.91176955; FRUSDR: 1.43. The benchmark results may need to be revised as additional testing is conducted. Performance results are based on testing as of November 15. 2018 and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure. 2Source – Intel-tested: 4K 70/30 RW Performance at Low Queue Depth. Test and System Configuration: CPU: Xeon Skylake Gold 6140 FCLGA14B 2.3GHz 24.75MB 140W 18 cores CD8067303405200 , CPU Sockets: 2, RAM Capacity: 32G, RAM Model: DDR4, RAM Stuffing: NA, DIMM Stots Populated: 2 slots, PCIe Attach: CPU (not PCH lane attach), Chipset: htel C620 chipset BIOS:

SE5C620.86B.00.01.0013.030920180427, Switch/ReTimer Model/Vendor. Cable - Oculink 800mm straight SFF-8611 Intel AXXCBL800CVCR, OS: CentOS 7.5, Kernet 4.14.50(LTS), FIO version: 3.5; NVMe Driver. Inbox, C-states: Disabled, Hyper Threading: Disabled, CPU Governor (through OS): Performance Mode. EIST (Speed Step). Intel Turbo Mode. Disabled, and P-states = Enabled. The benchmark results may need to be revised as additional testing is conducted. Performan ceresults are based on testing as of July 2018 and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure

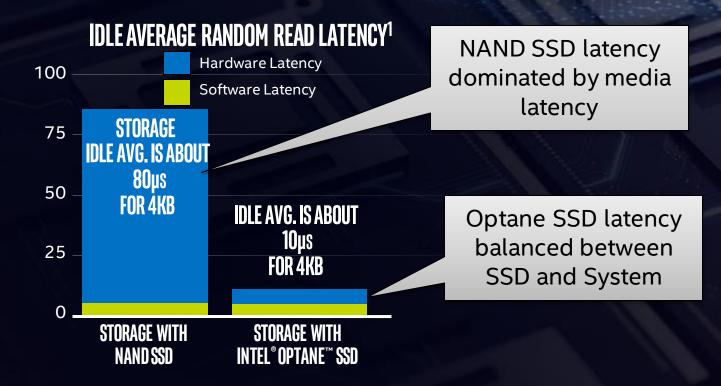
35 ource - hel-bested 4K Read Latency under 500 MB/s Write Workload. Measured using FIO.215. Tests document performance of components on a particular test, in specific systems. Differences in hardwae, software, or configuration will a fect actual performance actual performance actual performance actual performance actual performance actual performance actual performance. www.intel.combenchmarks. Common Contiguration - Intel 2U Server System, OS CentIOS 7.5, kernel 4.17.61 e17.x86_64, CPU 2 x hello Xeoroli 6.154 Gold @ 3.0 GHz (18 cores), RAM 256GB DDR @ 2666MHz. Configuration - Intel® Optime™ SSD DC P4600 16TB. Latency - Average read latency measured at QD1 during 4K Random Write operations using to -2.15. System BIOS: 00.01 0.013, ME Firmware: 04.00.04.294 BMC Firmware: 143.91/76655 FRUSDR: 1.43. The benchmark results may need to be revised as additional testing is conducted. Performance results are based on testing as of July 2018 and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure

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LATENCY IMPROVEMENT REQUIRES SYSTEM INNOVATION

Latency vs. Load: NAND SSD vs. Intel[®] Optane[™] SSD ² (Intel[®] DC P4610 3.2TB vs. Intel[®] Optane[™] SSD DC P4800x 375GB)





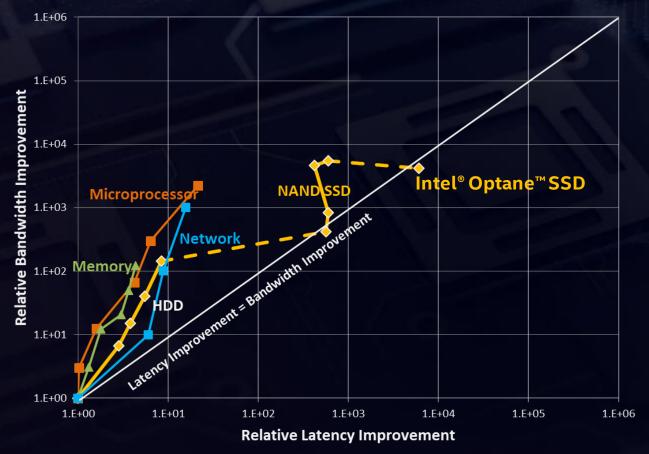
¹ Source – Intel+tested: Average read latency measured at queue depth 1 during 4k random write workload. Measured using RO 3.1. Common Configuration – Intel 2U Server System, OS CentOS 7.5, kernel 4.17.6-1.at7.x86_6.4, CPU 2 xIntel[®] Xeon[®] 6154 Gold @ 3.0GHz (18 cores), RAM 256GB DDR4 @ 2666MHz. Configuration – Intel[®] Optane[®] SSD DC P4800X 375GB and Intel[®] SSD DC P4800X 375GB and In

results are based on testing as of July 24, 2018 and may not reflect all publicly available security updates. See configuration disdosure for details. No product can be absolutely secure Software and workbads used in performance tests may have been **Oplimized** for performance only on Intel microprocessors. Performance tests, such as SYSmark and MobileMark, are measured using specific computer systems, components, software, operations and functions. Any change to any of those factors may cause the results to vary. You should consult other information and performance tests to assist you in fully evaluating your contemplated purchases, including the performance of that product when combined with other products. For more complete information visit <u>www.intel.com/bench.marks</u>.

² See Note on previous slide

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PERFORMANCE: TECHNOLOGY SCALING

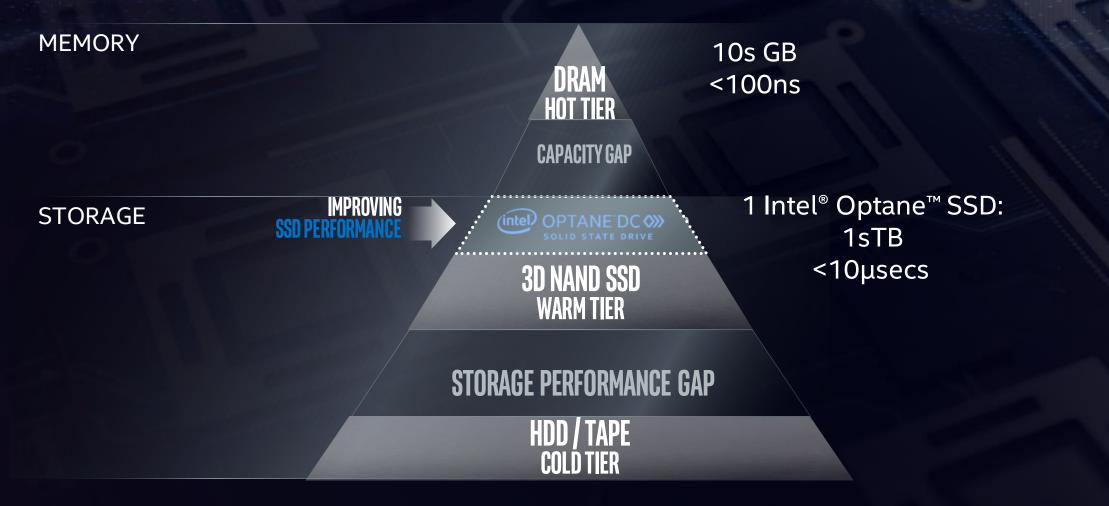


Source: "Latency lags Bandwidth" – David Patterson Comms. of the ACM, Oct 2004 Vol 47, No 10

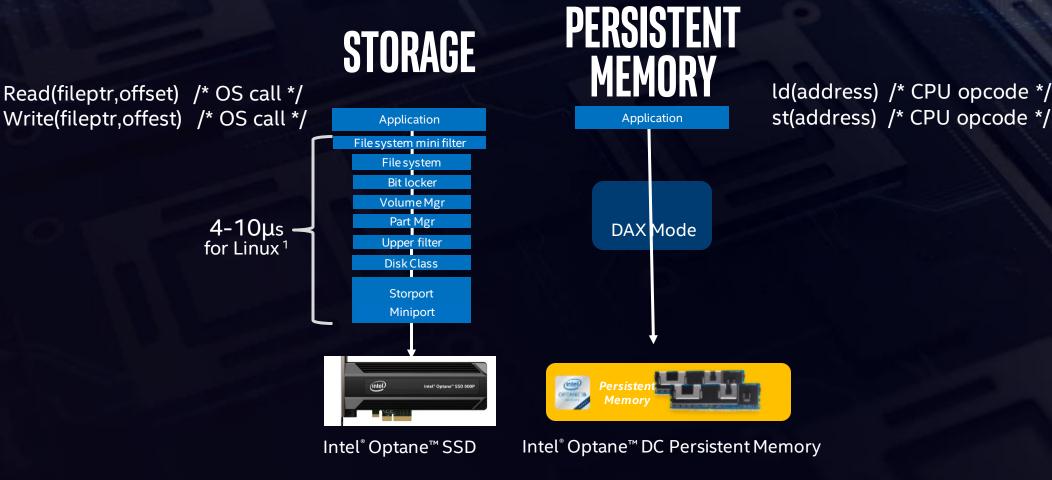
NAND and Optane SSD data points added by Intel Based on product brief specifications for Intel NAND and Optane SSDs available at <u>www.intel.com</u>

INTEL[®] OPTANE[™] SSDS PUT STORAGE BACK IN THROUGHPUT/LATENCY BALANCE

MEMORY AND STORAGE HIERARCHY



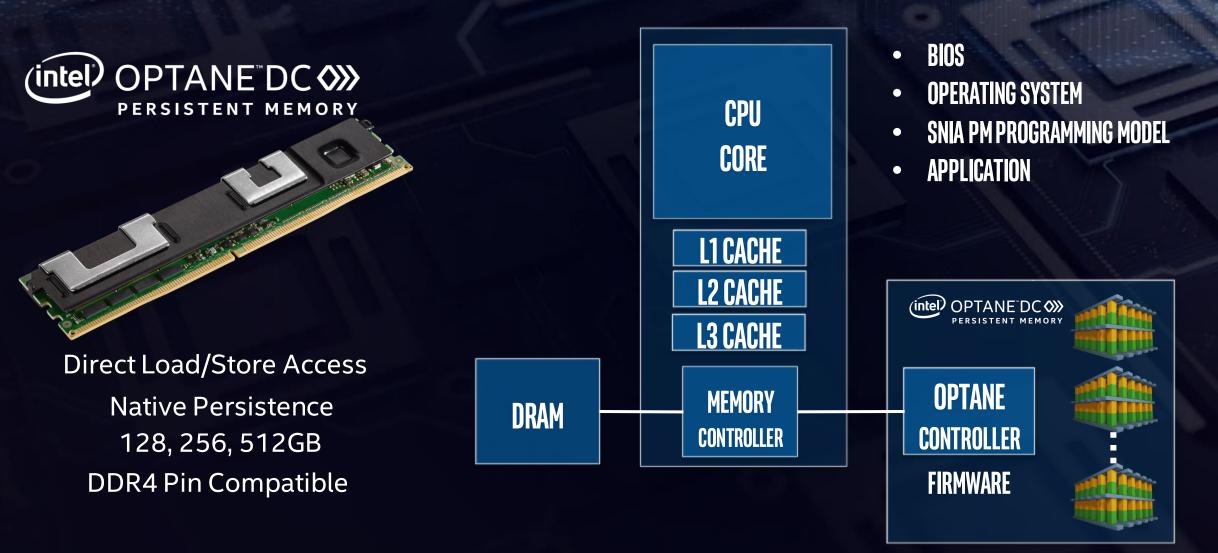
LOW LATENCY SOFTWARE PATH



1. Platform Storage Performance With 3D Xpoint Technology. Frank Hady, Annie Foong, Bryan Veal, Dan Williams, Proceedings of the IEEE. Vol 105, No. 9, Sept 2017 <a href="http://ieeexplore.ieee.org/stamp/stams

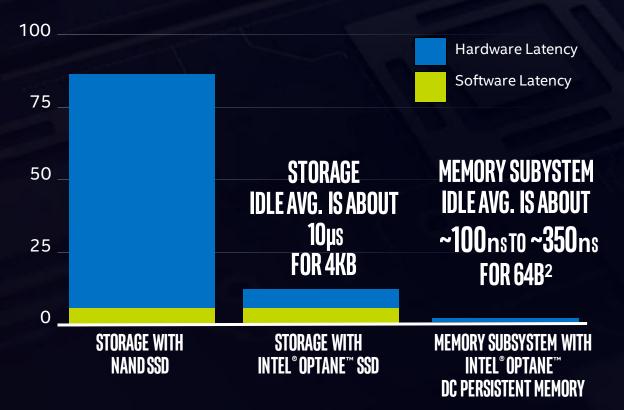
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PERSISTENT MEMORY PLATFORM SUPPORT



LOW LATENCY SYSTEM ACCESS TO PERSISTENT MEMORY

IDLE AVERAGE RANDOM READ LATENCY¹



¹ Source: Intel-tested: Average read latency measured at queue depth 1 during 4k random write workload. Measured using FIO 3.1. comparing Intel Reference platform with Optane[™] SSD DC P4800X 375GB and Intel[®] SSD DC P4600 1.6TB compared to SSDs commercially available as of July 1, 2018. Performance results are based on testing as of July 24, 2018 and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure. For more complete information about performance and benchmark results, visit www.intel.com/benchmarks.

² App Direct Mode, NeonCity, LBG B1 chipset, CLX B0 28 Core (QDF QQYZ), Memory Conf 192GB DDR4 (per socket) DDR 2666 MT/s, Optane DCPMM 128GB, BIOS 561.D09, BKC version WW48.5 BKC, Linux OS 4.18.8-100.fc27, Spectre/Meltdown Patched (1,2,3, 3a) © ISOTDAQ 2019. All Rights Reserved.

INTEL® OPTANE[™] PERSISTENT MEMORY : APP DIRECT MODE

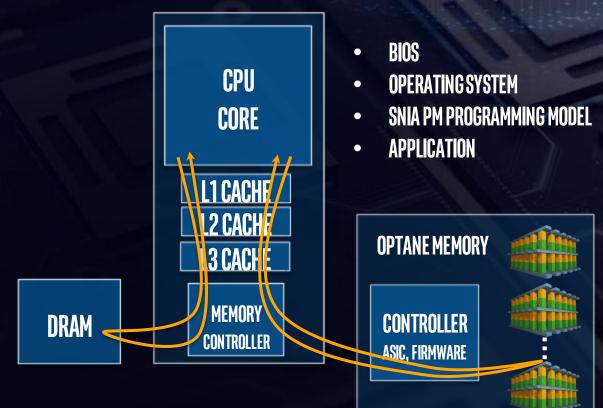


App Direct Mode provides the persistent memory programming model

- Reported to OS by ACPI
- Linux and Windows expose via "DAX" file systems

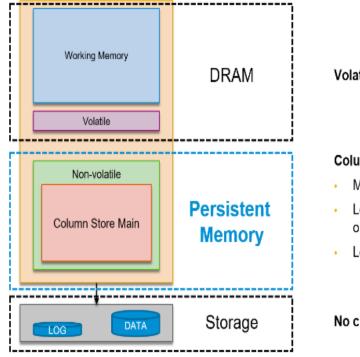
Several use cases supported by OS & PMDK APIs

- Persistent memory, non-paged (no DRAM footprint when accessed)
- Volatile App Direct, an explicit pool of volatile memory
- Storage over App Direct, a very fast SSD built on persistent memory



APP DIRECT USAGE EXAMPLE

SAP HANA controls what is placed in Persistent Memory and what remains in DRAM.



Volatile data structures remain in DRAM.

Column Store Main moves to Persistent Memory

- More than 95% of data in most HANA systems.
- Loading of tables into memory at startup becomes obsolete.
- Lower TCO, larger capacity.

No changes to the persistence.

Developer placed data structures

"SAP HANA knows which data structures benefit most from persistent memory. SAP HANA automatically detects persistent memory hardware and adjusts itself by automatically placing these data structures on persistent memory, while all others remain in DRAM"

- Column Store Main in Persistent Memory
 - 90% of the data footprint
 - Nonvolatile no initial load time
- High perf, volatile in DRAM
- SSDs still used for row store, column delta, replication, backups...

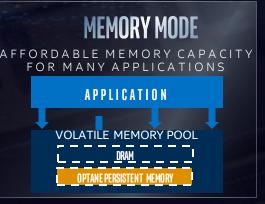
Source: "SAP HANA & Persistent Memory" – Andreas Schuster

Dec 3 2018, https://blogs.sap.com/2018/12/03/sap-hana-persistent-memory/

² App Direct Mode, NeonCity, LBG B1 chipset, CLX B0 28 Core (QDF QQYZ), Memory Conf 192GB DDR4 (per socket) DDR 2666 MT/s, Intel® Optane Data Center Persistent Memory 128GB, BIOS 561.D09, BKC version WW48.5 BKC, Linux OS 4.18.8-100.fc27, Spectre/Meltdown Patched (1,2,3,3a) © ISOTDAQ 2019. All Rights Reserved.

INTEL[®] OPTANE[™] PERSISTENT MEMORY :

MEMORY MODE

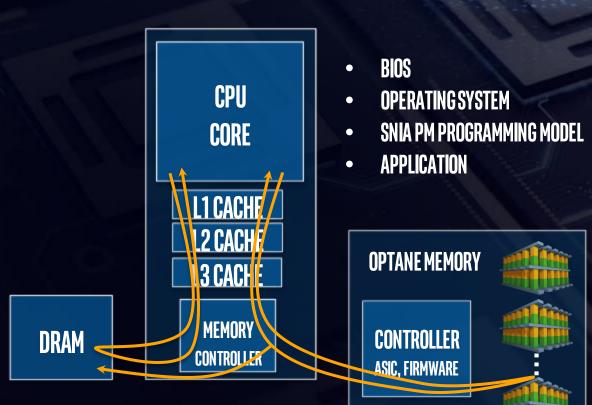


Memory Mode provides familiar volatile memory programming model

- Additional layer of caching: DRAM as WB cache
- Hardware managed, software sees very high capacity memory (6 TB)

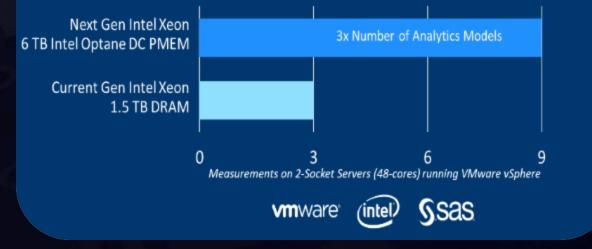
Range of use cases supported

- No software change big memory
- Applications/Algorithms changes for new hierarchy/capacity



MEMORY MODE USAGE EXAMPLE

Scalable Machine Learning and Analytics Performance without a GPU SAS Viya[®] 400 GB Gradient Boosting Models



Source: "Extending Memory Capacity with VMware vSphere and Upcoming Intel Optane Memory Technology" – Rich Brunner

Nov 6 2018, https://octo.vmware.com/vmware-and-intel-optane-dc-pmem/

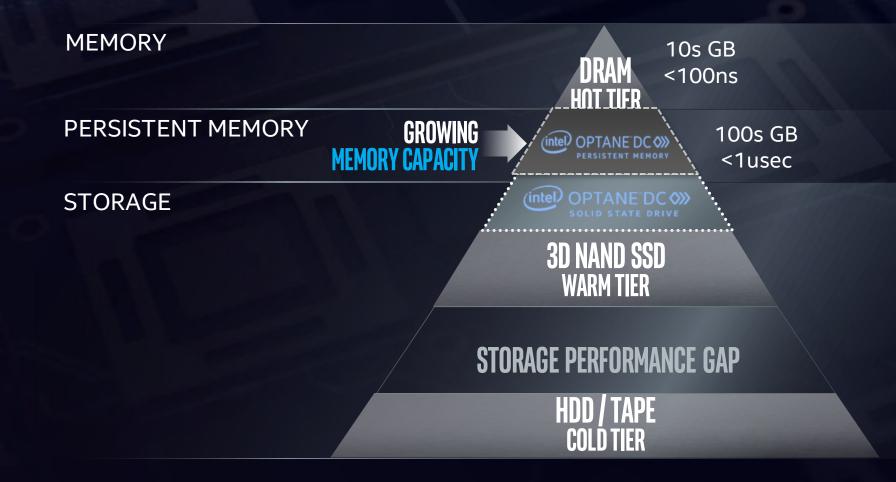
VMware vSphere* using memory mode:

"When used in memory mode, the new Intel memory technology can greatly increase the memory capacity available to software in a platform when compared with the capacity of DRAM. This increase in capacity requires no changes to your existing software, operating systems, or virtual machines."

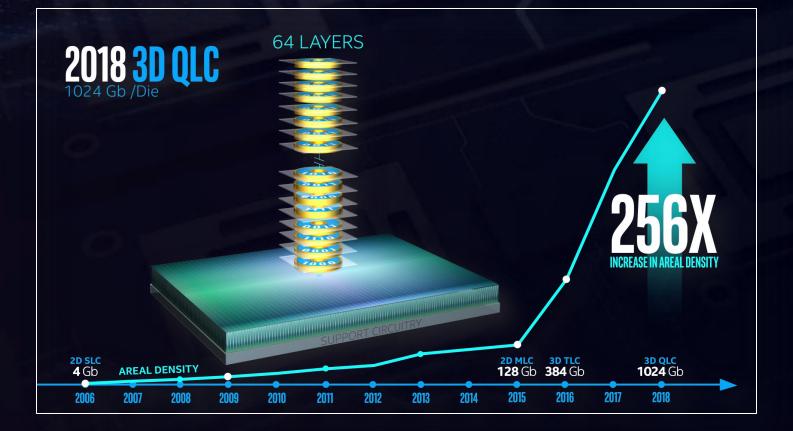
- Developer allocates VM memory images in "memory"
- Platform memory controller caches active VM data in DRAM for use

Performance results have been estimated based on SAS internal tests as of 11/05/2018 using future version of VMware vSphere, SAS Viya 400GB Gradient Boosting Models running Linux with Intel® Optane[™] DC persistent memory vs. DRAM-based server and may not reflect all publicly available security updates. As measured by VMWARE on system listed as 2-CPU socket server, Intel® Cascade lake, future version of Vmware cSphere, 6TB Intel® Optane[™] DC Persistent Memory in Memory Mode, versus 2-CPU socket server, Intel® Cascade lake, future version of Vmware cSphere, 1.5TB DDR4 DRAM 3x 3.6 TB SSD. Performance results are based on testing as of [INSERT DATE] and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure. For more complete information about performance and benchmark results, visit www.intel.com/benchmarks..

COMPLETE IN PERFORMANCE, CAPACITY, FIT



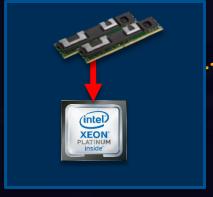
NAND TECHNOLOGY ADVANCEMENT





THE FUTURE OF DATA CENTER STORAGE & MEMORY

DATA/METATDATA CACHE IN PM V/INTEL® OPTANE™ DC PERSISTENT MEMORY



DATA STORAGE IN 1PB IN 1U w/intel° 3d Nand SSDs



COMPLETE IN PERFORMANCE, CAPACITY, FIT

